



THIS SPEC IS OBSOLETE

Spec No: 001-67737

Spec Title: CY7C199CN AUTOMOTIVE, 256-KBIT (32K X 8)  
STATIC RAM

Replaced by: None

## Features

- Fast access time: 12 ns
- Wide voltage range: 5.0 V ± 10% (4.5 V to 5.5 V)
- Complementary metal oxide semiconductor (CMOS) for optimum speed and power
- Transistor-transistor logic (TTL) compatible inputs and outputs
- Low CMOS standby power
- Automated power down when deselected
- Available in 28-pin SOJ package

## Functional Description

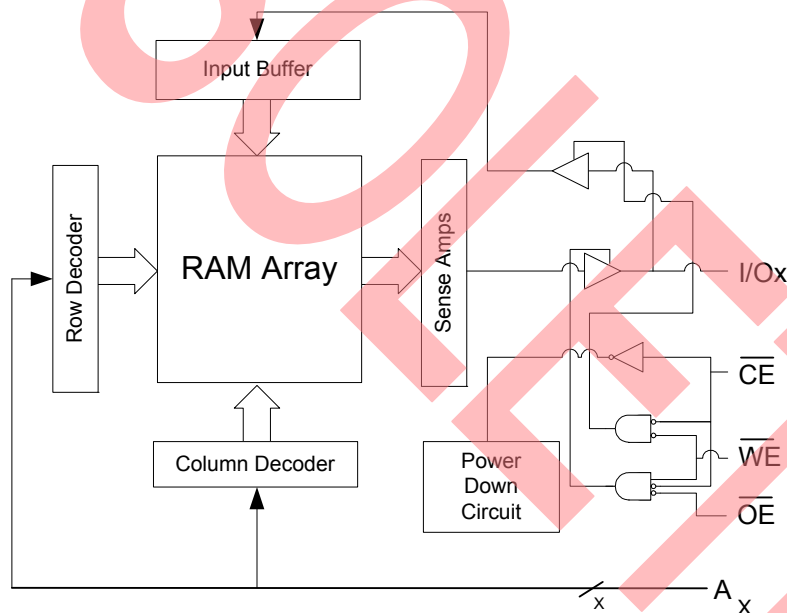
The CY7C199CN Automotive <sup>[1]</sup> is a high performance CMOS Asynchronous SRAM organized as 32K by 8 bits that supports an asynchronous memory interface. The device features an automatic power down feature that reduces power consumption when deselected.

See the [Truth Table on page 4](#) in this data sheet for a complete description of read and write modes.

The CY7C199CN Automotive is available in 28-pin Molded SOJ package.

For a complete list of related resources, [click here](#).

## Logic Block Diagram



## Product Portfolio

Description	-12	Unit
Maximum access time	12	ns
Maximum operating current	85	mA
Maximum CMOS standby current	10	mA

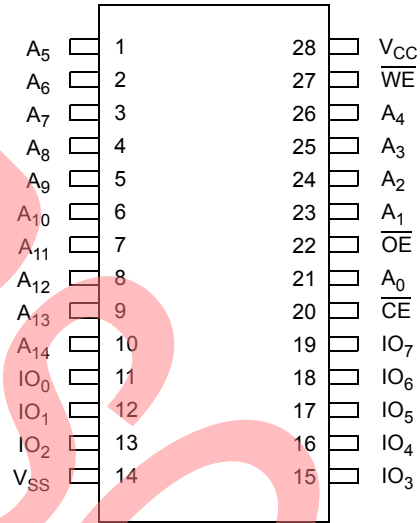
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Pin Layout and Specifications

Figure 1. 28-pin SOJ pinout



Note

1. For best practices recommendations, refer to the Cypress application note *System Design Guidelines* on [www.cypress.com](http://www.cypress.com).

**Pin Description**

Pin	Type	Description	SOJ
A <sub>x</sub>	Input	Address inputs	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 21, 23, 24, 25, 26
$\overline{\text{CE}}$	Control	Chip enable	20
IO <sub>x</sub>	Input or output	Data input outputs	11, 12, 13, 15, 16, 17, 18, 19
$\overline{\text{OE}}$	Control	Output enable	22
V <sub>CC</sub>	Supply	Power (5.0V)	28
V <sub>SS</sub>	Supply	Ground	14
$\overline{\text{WE}}$	Control	Write enable	27

**Truth Table**

$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{WE}}$	IO <sub>x</sub>	Mode	Power
H	X	X	High-Z	Deselect/power-down	Stand by (I <sub>SB</sub> )
L	L	H	Data-out	Read	Active (I <sub>CC</sub> )
L	X	L	Data-in	Write	Active (I <sub>CC</sub> )
L	H	H	High-Z	Selected, outputs disabled	Active (I <sub>CC</sub> )

## Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Parameter <sup>[2]</sup>	Description	Value	Unit
T <sub>STG</sub>	Storage temperature	-65 to +150	°C
T <sub>AMB</sub>	Ambient temperature with power applied (that is, case temperature)	-55 to +125	°C
V <sub>CC</sub>	Core supply voltage relative to V <sub>SS</sub>	-0.5 to +7.0	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC voltage applied to any pin relative to V <sub>SS</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>OUT</sub>	Output short-circuit current	20	mA
V <sub>ESD</sub>	Static discharge voltage (in accordance with MIL-STD-883, Method 3015)	> 2001	V
I <sub>LU</sub>	Latch-up current	> 200	mA

## Operating Range

Range	Ambient Temperature (T <sub>A</sub> )	Voltage Range (V <sub>CC</sub> )
Automotive-A	-40 °C to 85 °C	5.0 V ± 10%

## DC Electrical Characteristics

Over the Operating Range

Parameter <sup>[2]</sup>	Description	Condition	-12		Unit
			Min	Max	
V <sub>IH</sub>	Input HIGH voltage		2.2	V <sub>CC</sub> + 0.3	V
V <sub>IL</sub>	Input LOW voltage		-0.5	0.8	V
V <sub>OH</sub>	Output HIGH voltage	V <sub>CC</sub> = Min, I <sub>OH</sub> = -4.0 mA	2.4	-	V
V <sub>OL</sub>	Output LOW voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = 8.0 mA	-	0.4	V
I <sub>CC</sub>	V <sub>CC</sub> operating supply current	V <sub>CC</sub> = Max, I <sub>OUT</sub> = 0 mA, f = F <sub>max</sub> = 1/t <sub>RC</sub>	-	85	mA
I <sub>SB1</sub>	Automatic $\overline{CE}$ power- down current – TTL Inputs	Max V <sub>CC</sub> , $\overline{CE} \geq V_{IH}$ , V <sub>IN</sub> ≥ V <sub>IH</sub> or V <sub>IN</sub> ≤ V <sub>IL</sub> , f = F <sub>max</sub>	-	30	mA
I <sub>SB2</sub>	Automatic $\overline{CE}$ power- down current – CMOS Inputs	Max V <sub>CC</sub> , $\overline{CE} \geq V_{CC} - 0.3$ V, V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.3 V, or V <sub>IN</sub> ≤ 0.3 V, f = 0	-	10	mA
I <sub>OZ</sub>	Output leakage current	GND ≤ V <sub>I</sub> ≤ V <sub>CC</sub> , Output disabled	-5	+5	μA
I <sub>IX</sub>	Input leakage current	GND ≤ V <sub>I</sub> ≤ V <sub>CC</sub>	-5	+5	μA

**Note**

2. V<sub>IL(min)</sub> = -2.0 V for pulse durations of less than 20 ns.

### Capacitance

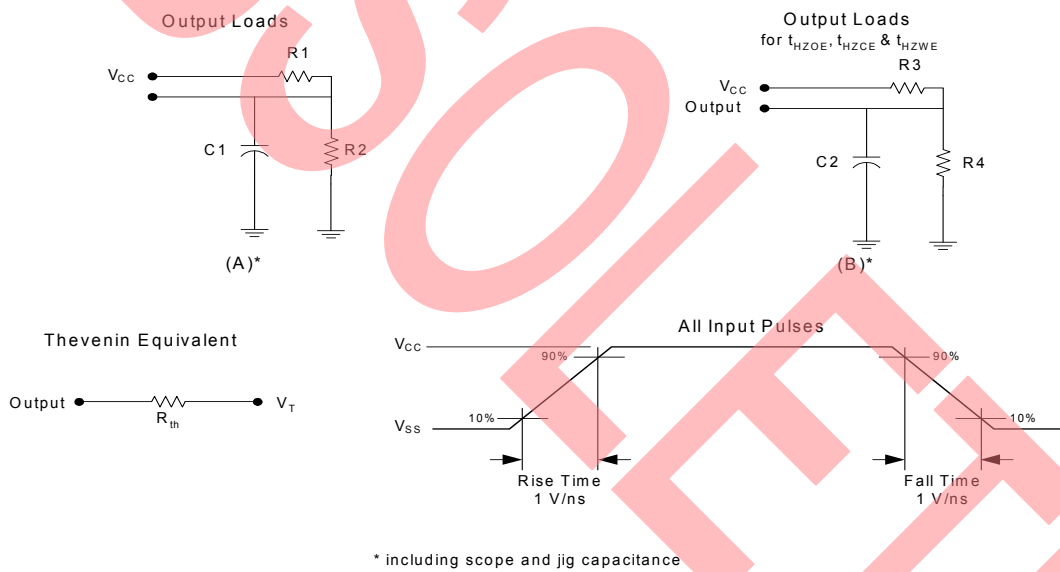
Parameter [3]	Description	Conditions	Max	Unit
C <sub>IN</sub>	Input capacitance	T <sub>A</sub> = 25 °C, f = 1 MHz, V <sub>CC</sub> = 5.0 V	8	pF
C <sub>OUT</sub>	Output capacitance		8	

### Thermal Resistance

Parameter [3]	Description	Conditions	SOJ	Unit
Θ <sub>JA</sub>	Thermal resistance (junction to ambient)	Still air, soldered on a 3 × 4.5 square inch, two-layer printed circuit board	79	°C/W
Θ <sub>JC</sub>	Thermal resistance (junction to case)		41.42	

### AC Test Loads

Figure 2. AC Test Loads



### AC Test Conditions

Parameter	Description	Nom	Unit
C1	Capacitor 1	30	pF
C2	Capacitor 2	5	
R1	Resistor 1	480	Ω
R2	Resistor 2	255	
R3	Resistor 3	480	
R4	Resistor 4	255	
R <sub>TH</sub>	Resistor Thevenin	167	
V <sub>TH</sub>	Voltage Thevenin	1.73	V

**Note**

3. Tested initially and after any design or process change that may affect these parameters.

**AC Electrical Characteristics**

Parameter [4, 5]	Description	-12		Unit
		Min	Max	
$t_{RC}$	Read cycle time	12	–	ns
$t_{AA}$	Address to data valid	–	12	ns
$t_{OHA}$	Data hold from address change	3	–	ns
$t_{ACE}$	$\overline{CE}$ to data valid	–	12	ns
$t_{DOE}$	$\overline{OE}$ to data valid	–	6	ns
$t_{LZOE}$	$\overline{OE}$ to low-Z [6]	0	–	ns
$t_{HZOE}$	$\overline{OE}$ to high-Z [6, 7]	–	5	ns
$t_{LZCE}$	$\overline{CE}$ to low-Z [6]	3	–	ns
$t_{HZCE}$	$\overline{CE}$ to high-Z [6, 7]	–	5	ns
$t_{PU}$	$\overline{CE}$ to power-up	0	–	ns
$t_{PD}$	$\overline{CE}$ to power-down	–	12	ns
$t_{WC}$	Write cycle time [8]	12	–	ns
$t_{SCE}$	$\overline{CE}$ to write end	9	–	ns
$t_{AW}$	Address setup to write end	9	–	ns
$t_{HA}$	Address hold from write end	0	–	ns
$t_{SA}$	Address setup to write start	0	–	ns
$t_{PWE}$	$\overline{WE}$ pulse width	8	–	ns
$t_{SD}$	Data setup to write end	8	–	ns
$t_{HD}$	Data hold from write end	0	–	ns
$t_{HZWE}$	$\overline{WE}$ LOW to high-Z [6, 7]	–	7	ns
$t_{LZWE}$	$\overline{WE}$ HIGH to low-Z [6]	3	–	ns

**Notes**

4. Test Conditions are based on a transition time of 3 ns or less and timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V.
5. The minimum write cycle pulse width for Write Cycle No. 3 ( $\overline{WE}$  Controlled,  $\overline{OE}$  LOW) should be equal to sum of  $t_{SD}$  and  $t_{HZWE}$ .
6. At any given temperature and voltage condition,  $t_{HZCE}$  is less than  $t_{LZCE}$ ,  $t_{HZOE}$  is less than  $t_{LZOE}$ , and  $t_{HZWE}$  is less than  $t_{LZWE}$  for any given device.
7.  $t_{HZOE}$ ,  $t_{HZCE}$ ,  $t_{HZWE}$  are specified as in part (b) of Figure 2 on page 6. Transitions are measured  $\pm 200$  mV from steady state voltage.
8. The internal memory write time is defined by the overlap of  $\overline{CE}$  LOW and  $\overline{WE}$  LOW.  $\overline{CE}$  and  $\overline{WE}$  must be LOW to initiate a write, and the transition of any of these signals can terminate the write. The input data setup and hold timing must be referenced to the leading edge of the signal that terminates the write.



### Timing Waveforms

Figure 3. Read Cycle No. 1 [9, 10]

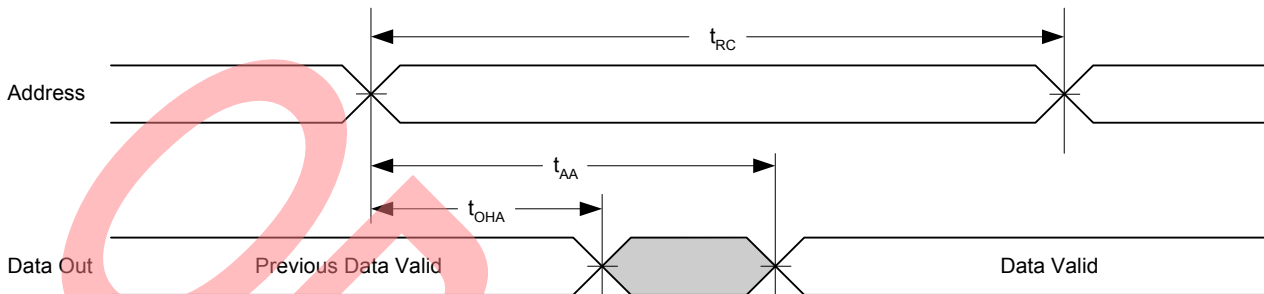
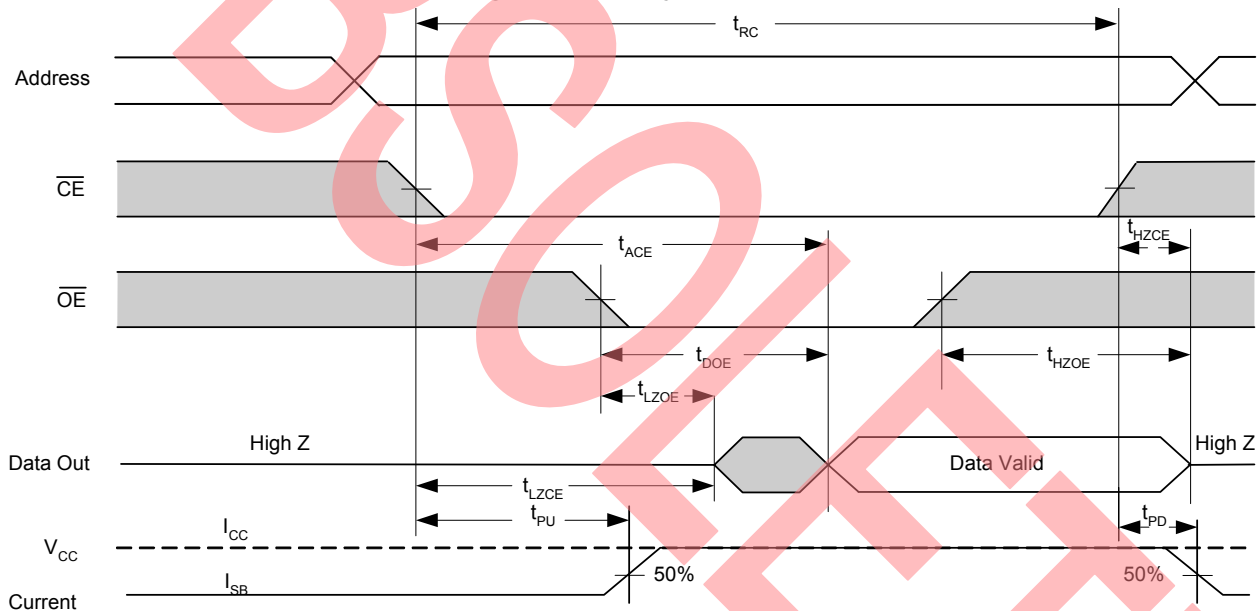


Figure 4. Read Cycle No. 2 [11, 12]



**Notes**

- 9. Device is continuously selected.  $\overline{OE} = V_{IL} = \overline{CE}$ .
- 10.  $\overline{WE}$  is HIGH for read cycle.
- 11. This cycle is  $\overline{OE}$  controlled and  $\overline{WE}$  is HIGH read cycle.
- 12. Address valid before or similar with  $\overline{CE}$  transition LOW.

Timing Waveforms (continued)

Figure 5. Write Cycle No. 1 ( $\overline{WE}$  Controlled) [13, 14, 15]

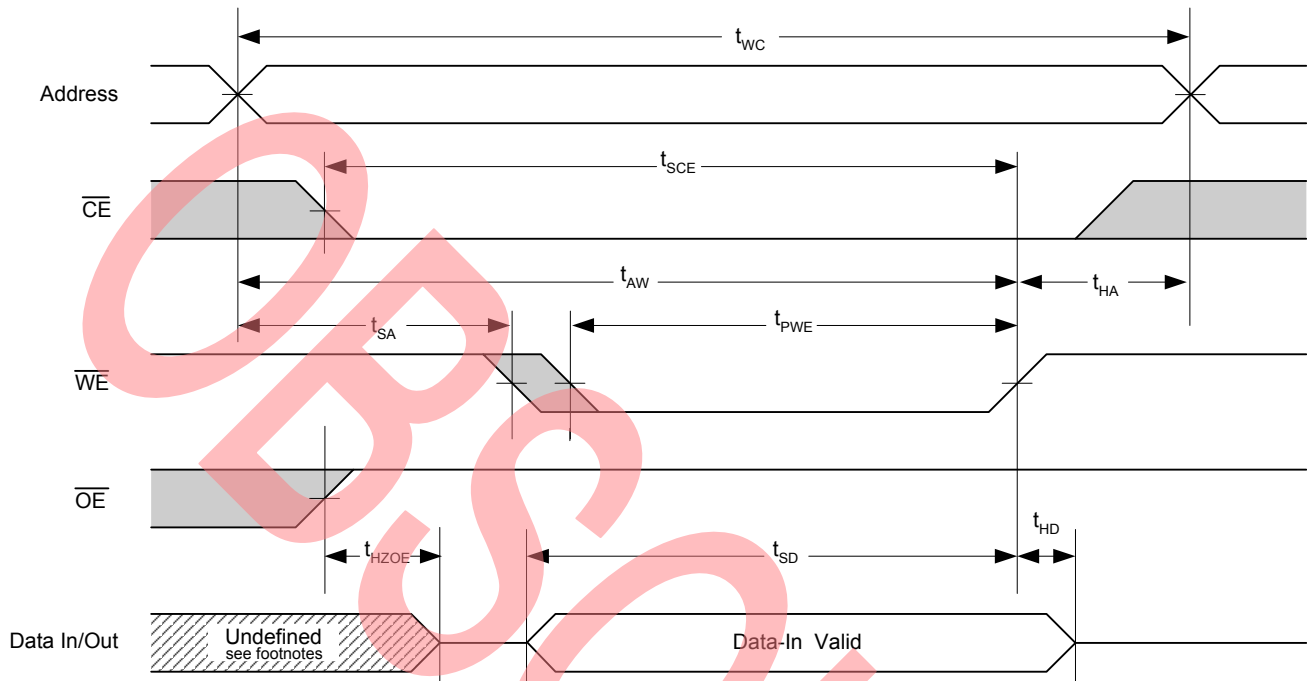
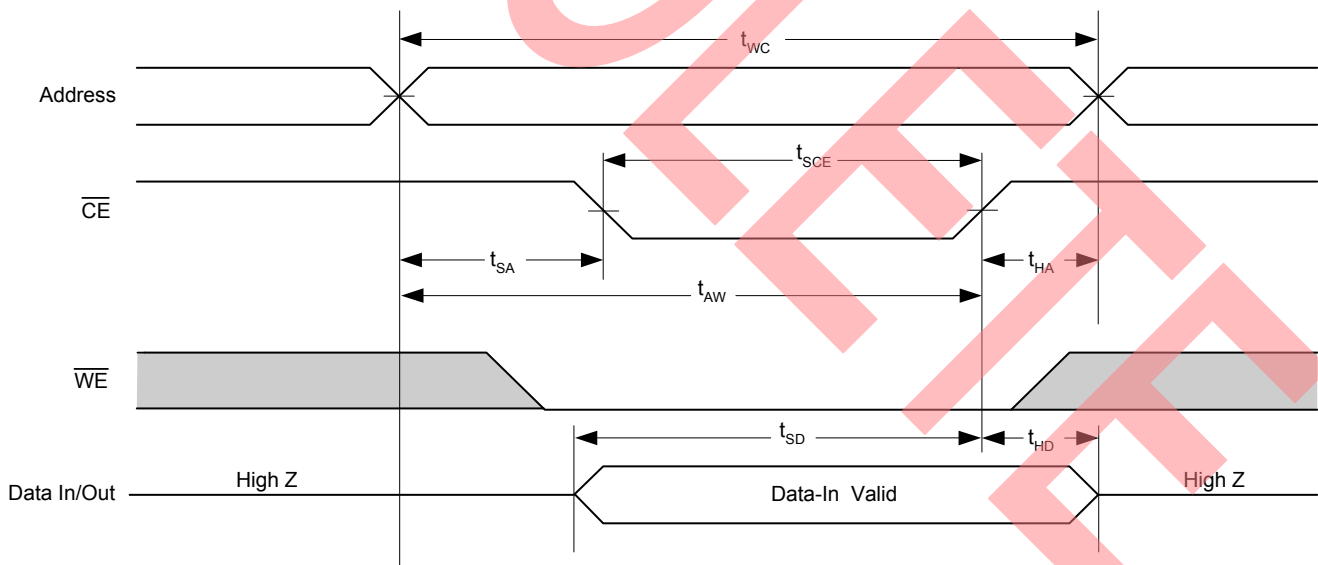


Figure 6. Write Cycle No. 2 ( $\overline{CE}$  Controlled) [14, 16, 17]

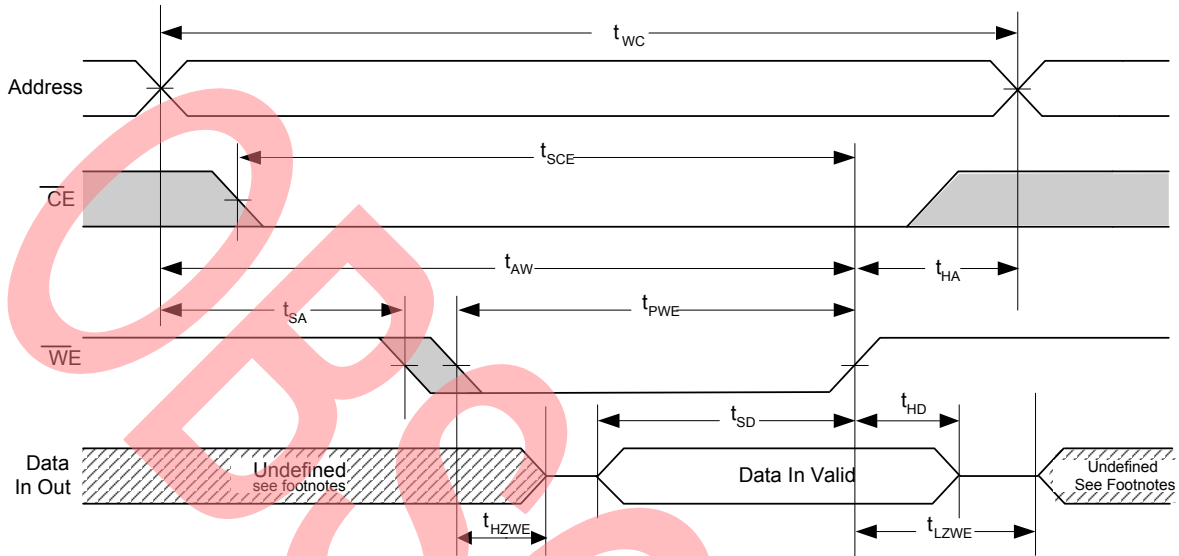


Notes

- 13. This cycle is  $\overline{WE}$  controlled,  $\overline{OE}$  is HIGH during write.
- 14. Data in and/or out is high impedance if  $\overline{OE} = V_{IH}$ .
- 15. During this period the IOs are in output state and input signals must not be applied.
- 16. This cycle is  $\overline{CE}$  controlled.
- 17. If  $\overline{CE}$  goes HIGH simultaneously with  $\overline{WE}$  going HIGH, the output remains in a high impedance state.

Timing Waveforms (continued)

Figure 7. Write Cycle No. 3 ( $\overline{WE}$  Controlled,  $\overline{OE}$  Low) <sup>[18]</sup>



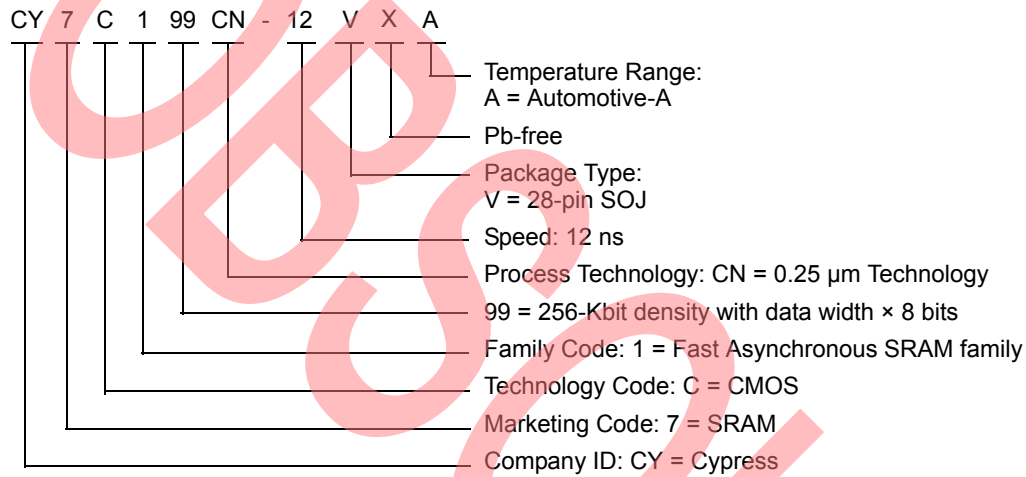
Note

18. The cycle is  $\overline{WE}$  controlled,  $\overline{OE}$  LOW. The minimum write cycle time is the sum of  $t_{HZWE}$  and  $t_{SD}$ .

**Ordering Information**

Speed (ns)	Ordering Code	Package Diagram	Package Type	Power Option	Operating Range
12	CY7C199CN-12VXA	51-85031	28-pin SOJ (300 Mils), Pb-free	Standard	Automotive-A

**Ordering Code Definitions**

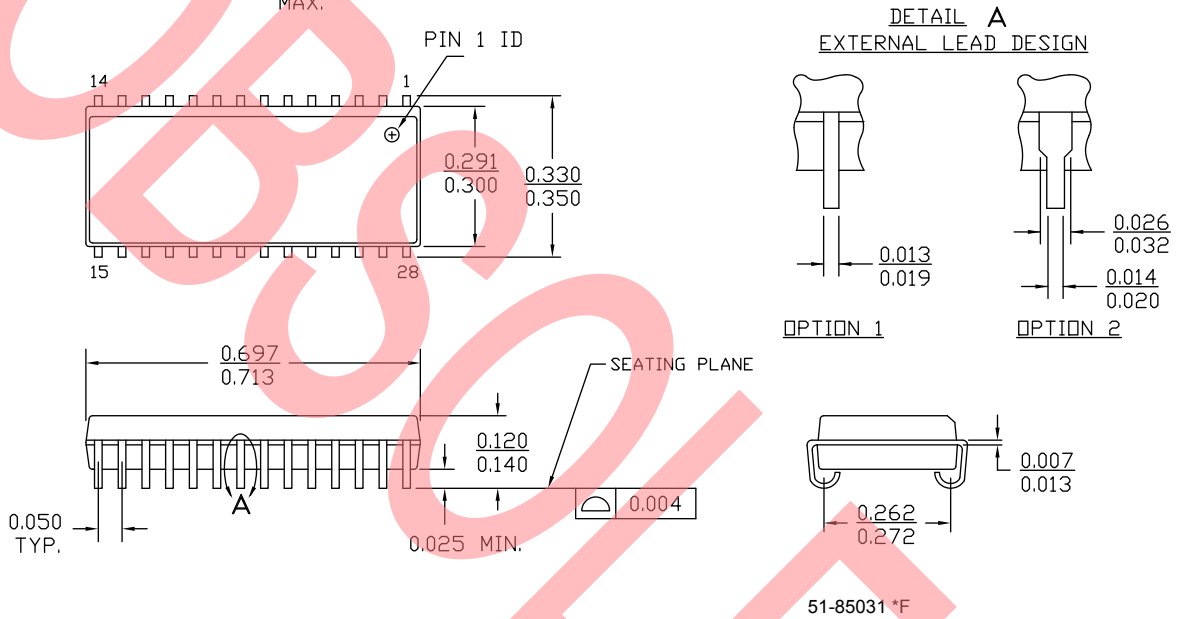


Package Diagrams

Figure 8. 28-pin SOJ (300 Mils) V28.3 (Molded SOJ V21) Package Outline, 51-85031

NOTE :

1. JEDEC STD REF MO088
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH  
MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.006 in (0.152 mm) PER SIDE
3. DIMENSIONS IN INCHES MIN.  
MAX.



**Acronyms**

Acronym	Description
$\overline{CE}$	Chip Enable
CMOS	Complementary Metal Oxide Semiconductor
I/O	Input/Output
$\overline{OE}$	Output Enable
SRAM	Static Random Access Memory
SOJ	Small Outline J-Lead
TTL	Transistor-Transistor Logic
$\overline{WE}$	Write Enable

**Document Conventions**

**Units of Measure**

Symbol	Unit of Measure
°C	degree Celsius
MHz	megahertz
μA	microampere
mA	milliampere
ns	nanosecond
Ω	ohm
%	percent
pF	picofarad
V	volt
W	watt

Document History Page

Document Title: CY7C199CN Automotive, 256-Kbit (32K × 8) Static RAM Document Number: 001-67737				
Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	3253367	PRAS	05/23/11	New data sheet. Separation of the automotive data sheet from CY7C199CN spec no. 001-06435 Rev. *D. Further rev of 001-06435 would include only industrial / commercial parts.
*A	4394563	VINI	05/30/2014	Updated <a href="#">Package Diagrams</a> : spec 51-85031 – Changed revision from *D to *E.  Updated to new template.  Completing Sunset Review.
*B	4546472	VINI	10/28/2014	Updated <a href="#">Maximum Ratings</a> : Referred Note 2 in “Parameter” column.  Updated <a href="#">AC Electrical Characteristics</a> : Added Note 5 and referred the same note in “Parameter” column.
*C	4745772	PSR	04/28/2015	Updated <a href="#">Functional Description</a> : Added “For a complete list of related resources, <a href="#">click here.</a> ” at the end. Updated <a href="#">Package Diagrams</a> : spec 51-85031 – Changed revision from *E to *F. Updated to new template. Completing Sunset Review.
*D	5307710	VINI	06/14/2016	Obsolete document. Completing Sunset Review.

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